



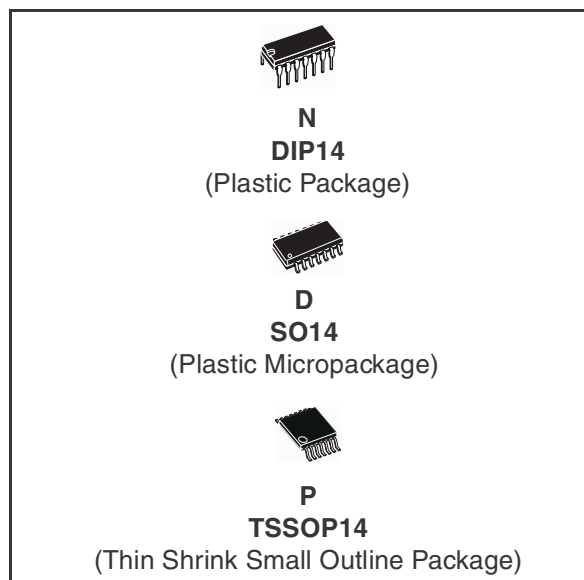
Micropower Quad CMOS Voltage Comparators

- Extremely low supply current: **9µA typ/comp.**
- Wide single supply range **2.7V to 16V** or dual supplies ($\pm 1.35V$ to $\pm 8V$)
- Extremely low input bias current: **1pA typ.**
- Extremely low input offset current: **1pA typ.**
- Input common-mode voltage range includes GND
- High input impedance: $10^{12}\Omega$ typ
- Fast response time: $1.5\mu s$ typ. for 5mV overdrive
- Pin-to-pin and functionally compatible with bipolar LM339

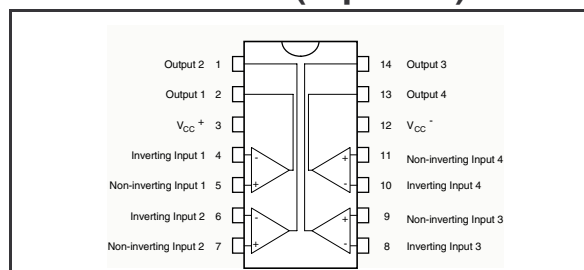
Description

The TS339 is a micropower CMOS quad voltage comparator with extremely low consumption of 9µA typ / comparator (20 times less than bipolar LM339). Similar performances are offered by the quad micropower comparator TS3704 with a push-pull CMOS output.

Thus response times remain similar to the LM339.



Pin Connection (top view)



Order Codes

Part Number	Temperature Range	Package	Packaging	Marking
TS339CN	0°C, +70°C	DIP14	Tube	TS339CN
TS339CD/CDT		SO-14	Tube or Tape & Reel	S339C
TS339IN	-40°C, +125°C	DIP14	Tube	TS339IN
TS339ID/IDT		SO-14	Tube or Tape & Reel	S339I
TS339IPT		TSSOP14 (Thin Shrink Outline Package)	Tape & Reel	S339I
TS339IYD/IYDT		SO-14 (automotive grade level)	Tube or Tape & Reel	S339IY

1 Absolute Maximum Ratings

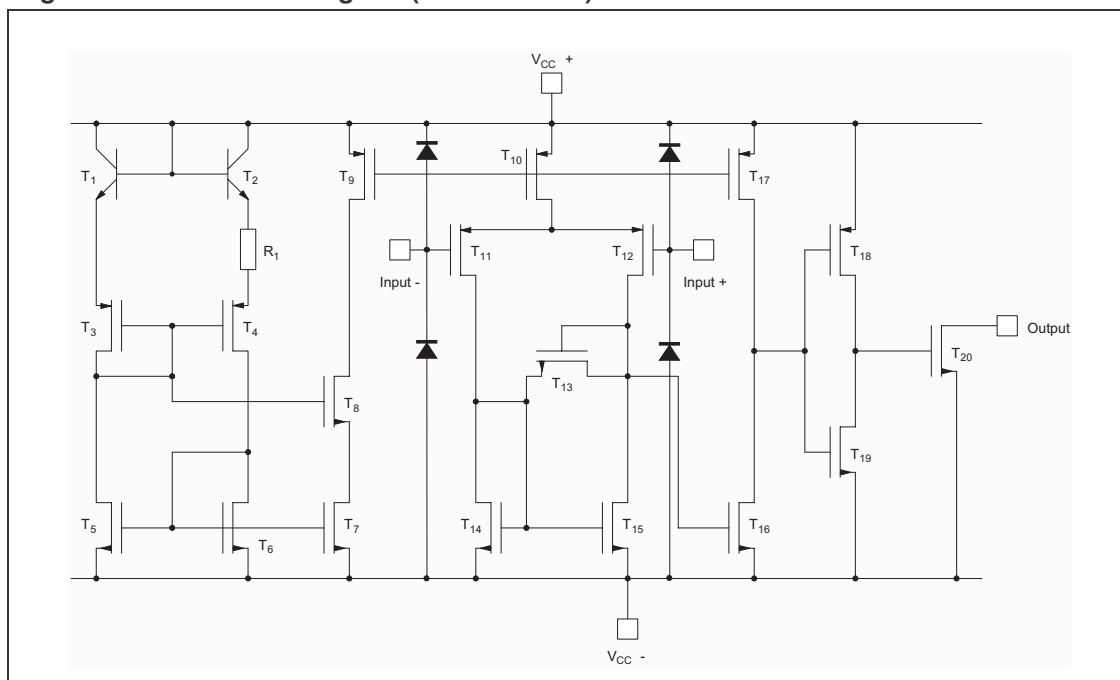
Table 1. Key parameters and their absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{CC}^{+}	Supply Voltage ⁽¹⁾	18	V
V_{id}	Differential Input Voltage ⁽²⁾	±18	V
V_i	Input Voltage ⁽³⁾	18	V
V_o	Output Voltage	18	V
I_o	Output Current	20	mA
I_F	Forward Current in ESD Protection Diodes on Inputs ⁽⁴⁾	50	mA
P_d	Power Dissipation ⁽⁵⁾ DIP14 SO14 TSSOP14	1500 830 710	mW
T_{stg}	Storage Temperature Range	-65 to +150	°C
ESD	HBM: Human Body Model ⁽⁶⁾	50	V
	MM: Machine Model ⁽⁷⁾	40	V
	CDM: Charged Device Model	800	V

1. All voltage values, except differential voltage, are with respect to network ground terminal.
2. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
3. Excursions of input voltages may exceed the power supply level. As long as the common mode voltage $[V_{icm}=(V_{in}^{+} + V_{in}^{-})/2]$ remains within the specified range, the comparator will provide a stable output state. However, the maximum current through the ESD diodes (I_F) of the input stage must strictly be observed.
4. Guaranteed by design.
5. P_d is calculated with $T_{amb} = +25^{\circ}\text{C}$, $T_j = +150^{\circ}\text{C}$ and
 $R_{thja} = 80^{\circ}\text{C/W}$ for DIP14 package
 $R_{thja} = 150^{\circ}\text{C/W}$ for SO14 package
 $R_{thja} = 175^{\circ}\text{C/W}$ for TSSOP14 package
6. Human body model, 100pF discharged through a 1.5kΩ resistor into pin of device.
7. Machine model ESD, a 200pF cap is charged to the specified voltage, then discharged directly into the IC with no external series resistor (internal resistor < 5Ω), into pin to pin of device.

2 Typical Application Schematics

Figure 1. Schematic diagram (for 1/4 TS339)



3 Electrical Characteristics

Table 2. $V_{CC}^+ = 3V$, $V_{CC}^- = 0V$, $T_{amb} = 25^\circ C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage ⁽¹⁾ $V_{ic} = 1.5V$ $T_{min.} \leq T_{amb} \leq T_{max.}$			5 6.5	mV
I_{io}	Input Offset Current ⁽²⁾ $V_{ic} = 1.5V$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1	300	pA
I_{ib}	Input Bias Current ⁽²⁾ $V_{ic} = 1.5V$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1	600	pA
V_{icm}	Input Common Mode Voltage Range $T_{min.} \leq T_{amb} \leq T_{max.}$	0 0		$V_{CC}^+ - 1.2$ $V_{CC}^+ - 1.5$	V
CMR	Common-mode Rejection Ratio $V_{ic} = V_{icm \text{ min.}}$		70		dB
SVR	Supply Voltage Rejection Ratio $V_{CC}^+ = 3V \text{ to } 5V$		70		dB
I_{OH}	High Level Output Current $V_{id} = +1V$, $V_{OH} = 3V$ $T_{min.} \leq T_{amb} \leq T_{max.}$		2	40 1000	nA
V_{OL}	Low Level Output Voltage $V_{id} = -1V$, $I_{OL} = +6mA$ $T_{min.} \leq T_{amb} \leq T_{max.}$		400	550 800	mV
I_{CC}	Supply Current (each comparator) No load - Outputs low $T_{min.} \leq T_{amb} \leq T_{max.}$		9	20 25	μA
t_{PLH}	Response Time Low to High $V_{ic} = 0V$, $f = 10kHz$, $T_{min.} \leq T_{amb} \leq T_{max.}$, $C_L = 50pF$, Overdrive = 5mV TTL Input		1.5 0.7		μs
t_{PHL}	Response Time High to Low $V_{ic} = 0V$, $f = 10kHz$, $R_L = 5.1k\Omega$, $C_L = 50pF$, Overdrive = 5mV TTL Input		2.5 0.08		μs

1. The specified offset voltage is the maximum value required to drive the output up to 2.5V or down to 0.3V.
2. Maximum values including unavoidable inaccuracies of the industrial test.

Table 3. $V_{CC}^+ = 5V$, $V_{CC}^- = 0V$, $T_{amb} = 25^\circ C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage ⁽¹⁾ $V_{ic} = 2.5V$, $V_{CC}^+ = 5V$ to $10V$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1.4	5 6.5	mV
I_{io}	Input Offset Current ⁽²⁾ $V_{ic} = 2.5V$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1	300	pA
I_{ib}	Input Bias Current ⁽²⁾ $V_{ic} = 2.5V$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1	600	pA
V_{icm}	Input Common Mode Voltage Range $T_{min.} \leq T_{amb} \leq T_{max.}$	0 0		$V_{CC}^+ - 1.2$ $V_{CC}^+ - 1.5$	V
CMR	Common-mode Rejection Ratio $V_{ic} = 0V$		75		dB
SVR	Supply Voltage Rejection Ratio $V_{CC}^+ = +5V$ to $+10V$		85		dB
I_{OH}	High Level Output Voltage $V_{id} = 1V$, $V_{OH} = +5V$ $T_{min.} \leq T_{amb} \leq T_{max.}$		27	40 1000	nA
V_{OL}	Low Level Output Voltage $V_{id} = -1V$, $I_{OL} = 6mA$ $T_{min.} \leq T_{amb} \leq T_{max.}$		260	400 650	mV
I_{CC}	Supply Current (each comparator) No load - Outputs low $T_{min.} \leq T_{amb} \leq T_{max.}$		10	20 25	μA
t_{PLH}	Response Time Low to High $V_{ic} = 0V$, $f = 10kHz$, $R_L = 5.1k\Omega$, $C_L = 15pF$, Overdrive = 5mV Overdrive = 10mV Overdrive = 20mV Overdrive = 40mV TTL Input		1.5 1.2 1.1 0.9 0.8		μs
t_{PHL}	Response Time High to Low $V_{ic} = 0V$, $f = 10kHz$, $R_L = 5.1k\Omega$, $C_L = 15pF$, Overdrive = 5mV Overdrive = 10mV Overdrive = 20mV Overdrive = 40mV TTL Input		2.5 1.9 1.2 0.8 0.08		μs
t_f	Fall time $f = 10kHz$, $C_L = 50pF$, $R_L = 5.1k\Omega$, Overdrive 50mV		30		ns

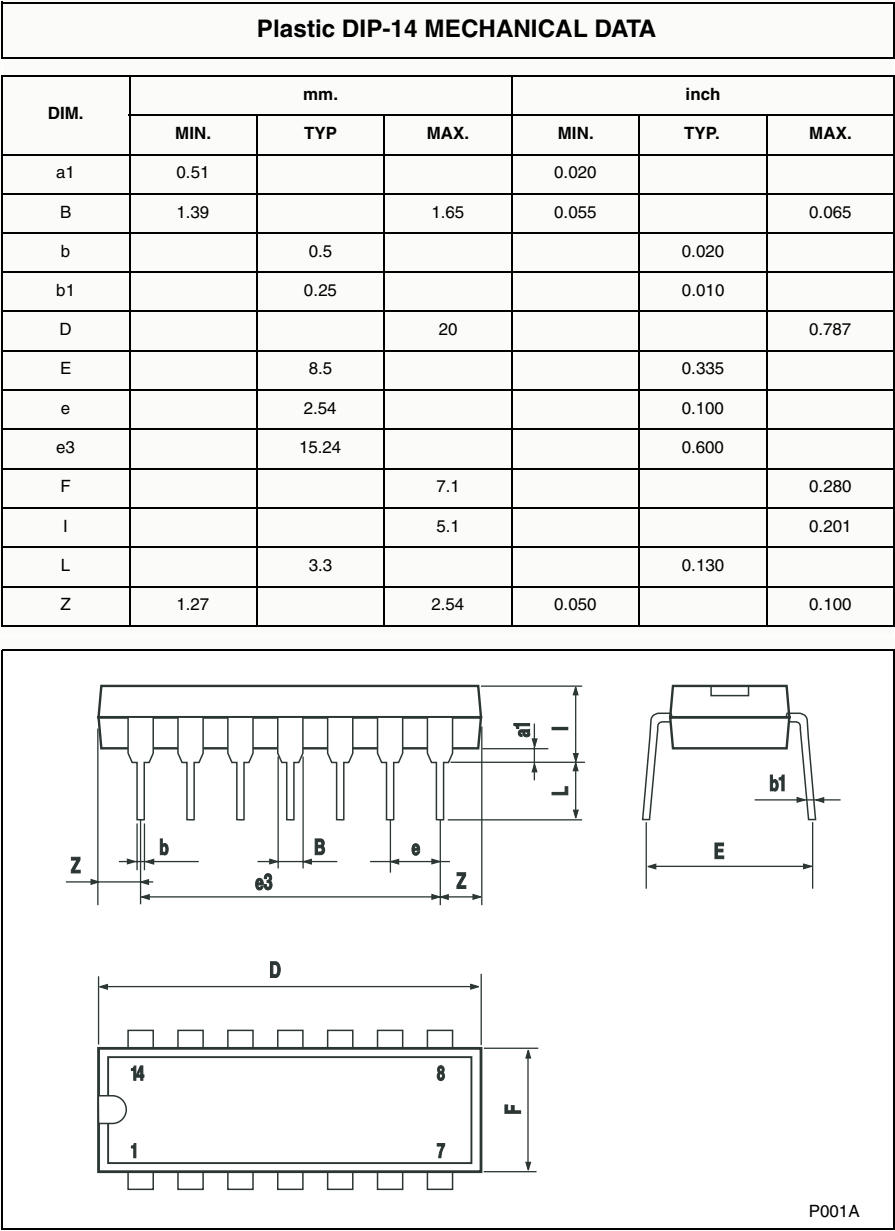
1. The specified offset voltage is the maximum value required to drive the output up to 4.5V or down to 0.3V.

2. Maximum values including unavoidable inaccuracies of the industrial test.

4 Package Mechanical Data

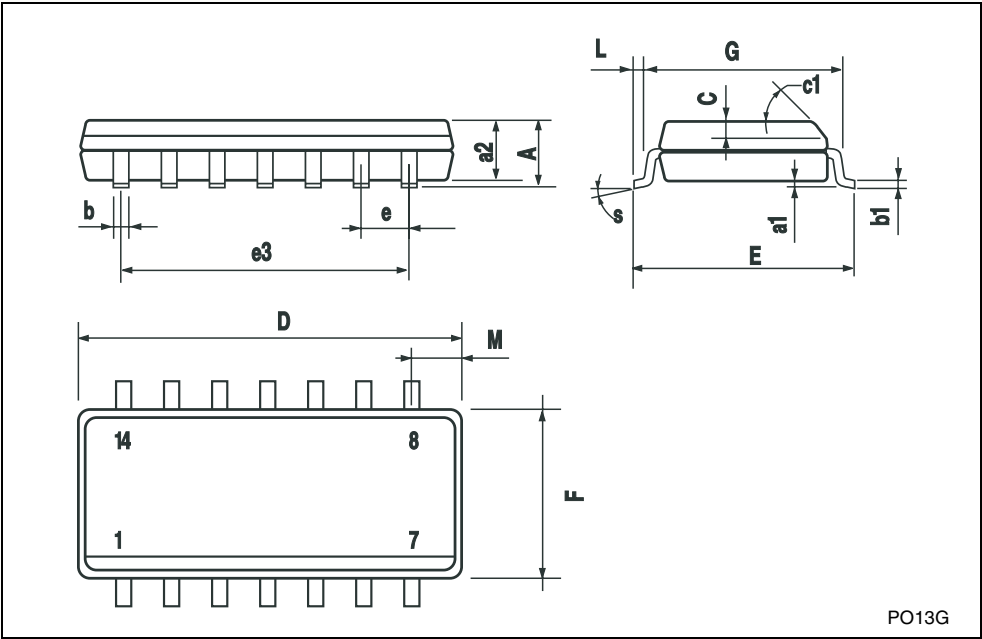
In order to meet environmental requirements, ST offers these devices in ECOPACK[®] packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com.

4.1 DIP14 Package



4.2 SO-14 Package

SO-14 MECHANICAL DATA						
DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.68			0.026
S	8° (max.)					

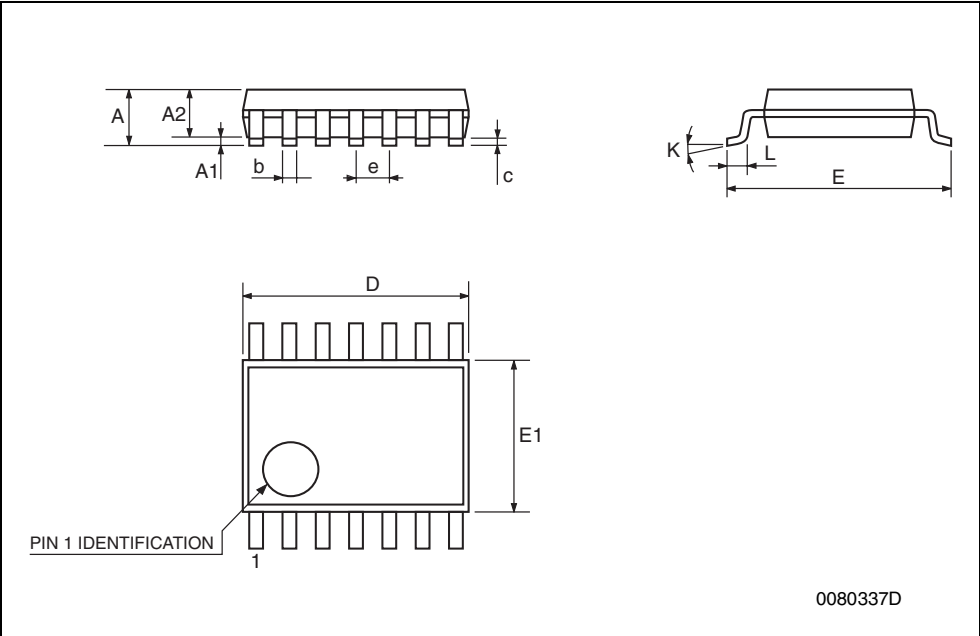


PO13G

4.3 TSSOP14 Package

TSSOP14 MECHANICAL DATA

DIM.	mm.			inch		
	MIN.	TYP	MAX.	MIN.	TYP.	MAX.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030



5 Revision History

Date	Revision	Changes
Jan. 2003	1	Initial release.
Aug. 2005	2	1 - PPAP references inserted in the datasheet see <i>Table : Order Codes on page 1</i> . 2 - ESD protection inserted in <i>Table 1: Key parameters and their absolute maximum ratings on page 2</i> .

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